

September 1983 Revised January 2005

MM74HC02 Quad 2-Input NOR Gate

General Description

The MM74HC02 NOR gates utilize advanced silicon-gate CMOS technology to achieve operating speeds similar to LS-TTL gates with the low power consumption of standard CMOS integrated circuits. All gates have buffered outputs, providing high noise immunity and the ability to drive 10 LS-TTL loads. The 74HC logic family is functionally as well as pin-out compatible with the standard 74LS logic family. All inputs are protected from damage due to static discharge by internal diode clamps to $V_{\rm CC}$ and ground.

Features

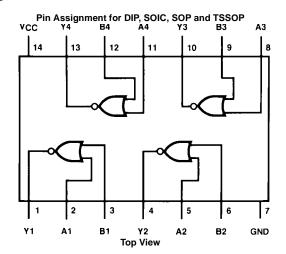
- Typical propagation delay: 8 ns
- Wide power supply range: 2-6V
- Low quiescent supply current: 20 µA maximum (74HC Series)
- Low input current: 1 µA maximum
- High output current: 4 mA minimum

Ordering Code:

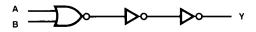
Order Number	Package Number	Package Description				
MM74HC02M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow				
MM74HC02SJ	M14D	Pb-Free 14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide				
MM74HC02MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide				
MM74HC02MTCX_NL	MTC14	Pb-Free 14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide				
MM74HC02N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide				

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code. (Tape and Reel not available in N14A.) Pb-Free package per JEDEC J-STD-020B.

Connection Diagram



Logic Diagram



Absolute Maximum Ratings(Note 1)

(Note 2)

(/	
Supply Voltage (V _{CC})	-0.5 to +7.0V
DC Input Voltage (V _{IN})	-1.5 to V_{CC} +1.5V
DC Output Voltage (V _{OUT})	-0.5 to V_{CC} $+0.5V$
Clamp Diode Current (I _{IK} , I _{OK})	±20 mA
DC Output Current, per pin (I _{OUT})	±25 mA
DC V _{CC} or GND Current, per pin	
(I _{CC})	±50 mA
Storage Temperature Range (T _{STG})	-65°C to $+150^{\circ}\text{C}$
Power Dissipation (P _D)	
(Note 3)	600 mW
S.O. Package only	500 mW
Lead Temperature (T _L)	
(Soldering 10 seconds)	260°C

Recommended Operating Conditions

	Min	Max	Units	
Supply Voltage (V _{CC})	2	6	V	
DC Input or Output Voltage	0	V_{CC}	V	
(V_{IN}, V_{OUT})				
Operating Temperature Range (T_A) -40 $+125$				
Input Rise or Fall Times				
(t_r, t_f) $V_{CC} = 2.0V$		1000	ns	
$V_{CC} = 4.5V$		500	ns	
$V_{CC} = 6.0V$		400	ns	

Note 1: Absolute Maximum Ratings are those values beyond which damage to the device may occur.

Note 2: Unless otherwise specified all voltages are referenced to ground.

Note 3: Power Dissipation temperature derating — plastic "N" package: –12 mW/°C from 65°C to 85°C.

DC Electrical Characteristics (Note 4)

Symbol	Parameter	Conditions	v _{cc}	$T_A = 25^{\circ}C$		T _A = -40 to 85°C	$T_A = -40$ to $125^{\circ}C$	Units
Syllibol		Conditions	*cc	Тур		Guaranteed L		
V _{IH}	Minimum HIGH Level		2.0V		1.5	1.5	1.5	V
	Input Voltage		4.5V		3.15	3.15	3.15	V
			6.0V		4.2	4.2	4.2	V
V _{IL}	Maximum LOW Level		2.0V		0.5	0.5	0.5	V
	Input Voltage		4.5V		1.35	1.35	1.35	V
			6.0V		1.8	1.8	1.8	V
V _{OH}	Minimum HIGH Level	$V_{IN} = V_{IL}$						
	Output Voltage	$ I_{OUT} \le 20 \ \mu A$	2.0V	2.0	1.9	1.9	1.9	V
			4.5V	4.5	4.4	4.4	4.4	V
			6.0V	6.0	5.9	5.9	5.9	V
		$V_{IN} = V_{IL}$						
		$ I_{OUT} \le 4.0 \text{ mA}$	4.5V	4.2	3.98	3.84	3.7	V
		$ I_{OUT} \le 5.2 \text{ mA}$	6.0V	5.7	5.48	5.34	5.2	V
V _{OL}	Maximum LOW Level	$V_{IN} = V_{IH}$ or V_{IL}						
	Output Voltage	$ I_{OUT} \leq 20~\mu A$	2.0V	0	0.1	0.1	0.1	V
			4.5V	0	0.1	0.1	0.1	V
			6.0V	0	0.1	0.1	0.1	V
		$V_{IN} = V_{IH}$ or V_{IL}						
		$ I_{OUT} \le 4.0 \text{ mA}$	4.5V	0.2	0.26	0.33	0.4	V
		$ I_{OUT} \le 5.2 \text{ mA}$	6.0V	0.2	0.26	0.33	0.4	V
I _{IN}	Maximum Input	$V_{IN} = V_{CC}$ or GND	6.0V		±0.1	±1.0	±1.0	μΑ
	Current							
I _{CC}	Maximum Quiescent	$V_{IN} = V_{CC}$ or GND	6.0V		2.0	20	40	μΑ
	Supply Current	$I_{OUT} = 0 \mu A$						

Note 4: For a power supply of 5V \pm 10% the worst case output voltages (V_{OH} , and V_{OL}) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at V_{CC} =5.5V and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst case leakage current (I_{IN} , I_{CC} , and I_{OZ}) occur for CMOS at the higher voltage and so the 6.0V values should be used.

AC Electrical Characteristics

 $V_{CC} = 5V$, $T_A = 25^{\circ}C$, $C_L = 15$ pF, $t_r = t_f = 6$ ns

Symbol	Parameter	Conditions	Тур	Guaranteed Limit	Units
t _{PHL} , t _{PLH}	Maximum Propagation Delay		8	15	ns

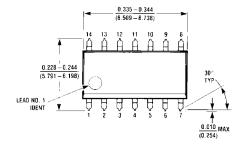
AC Electrical Characteristics

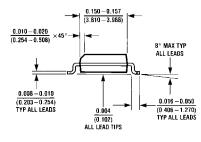
 $\text{V}_{CC} = 2.0 \text{V}$ to 6.0V, $C_L = 50$ pF, $t_\text{f} = t_\text{f} = \text{6}$ ns (unless otherwise specified)

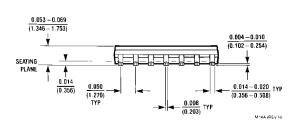
Symbol	Parameter	Conditions	v _{cc}	T _A = 25°C		$T_A = -40 \text{ to } 85^{\circ}\text{C}$	T _A = -55 to 125°C	Units
	i arameter			Typ Guaranteed Limits				Uillis
t _{PHL} , t _{PLH}	Maximum Propagation		2.0V	45	90	113	134	ns
	Delay		4.5V	9	18	23	27	ns
			6.0V	8	15	19	23	ns
t _{TLH} , t _{THL}	Maximum Output Rise		2.0V	30	75	95	110	ns
	and Fall Time		4.5V	8	15	19	22	ns
			6.0V	7	13	16	19	ns
C _{PD}	Power Dissipation	(per gate)		20				pF
	Capacitance (Note 5)							
C _{IN}	Maximum Input			5	10	10	10	pF
	Capacitance							

Note 5: C_{PD} determines the no load dynamic power consumption, $P_D = C_{PD} \ V_{CC}^2 \ f + I_{CC} \ V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} \ V_{CC} \ f + I_{CC}$.

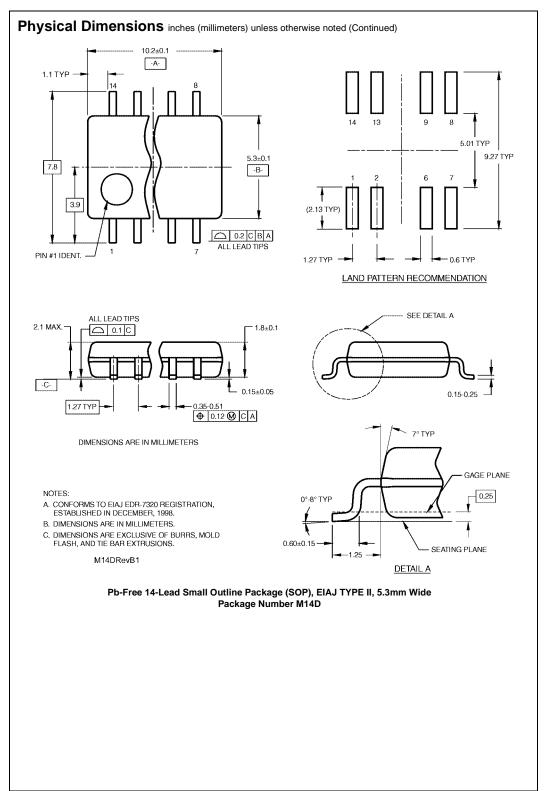
Physical Dimensions inches (millimeters) unless otherwise noted



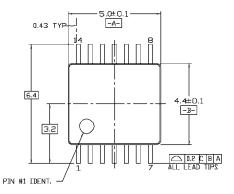


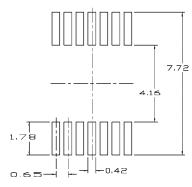


14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Package Number M14A

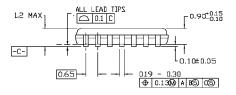


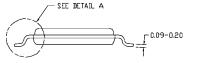
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)





LAND PATTERN RECOMMENDATION

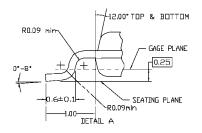




NOTES:

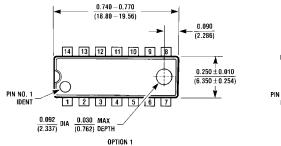
- A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB_ REF NOTE 6, DATED 7/93
- B. DIMENSIONS ARE IN MILLIMETERS
- D. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS D. DIMENSIONING AND TOLERANCES PER ANSI Y14.5M, 1982

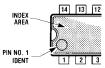
MTC14revD



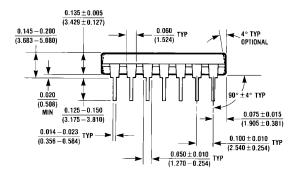
14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide Package Number MTC14

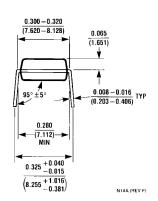
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)





OPTION 02





14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide Package Number N14A

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